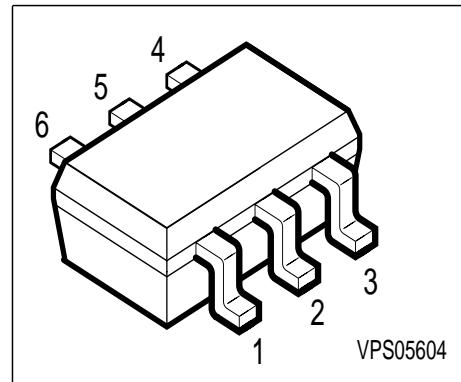
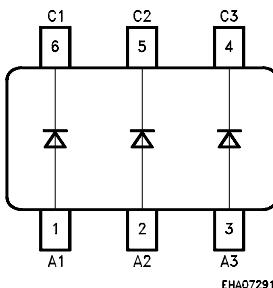
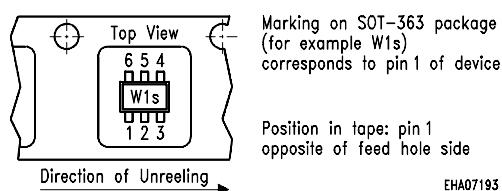


### Silicon Switching Diode Array

- For high-speed switching applications
- Internal (galvanic) isolated Diodes in one package

### Tape loading orientation



Type	Marking	Ordering Code	Pin Configuration						Package
BAS 16S	A6s	Q62702-A1241	1=A1	2=A2	3=A3	4=C3	5=C2	6=C1	SOT-363

### Maximum Ratings

Parameter	Symbol	Value	Unit
Diode reverse voltage	$V_R$	75	V
Peak reverse voltage	$V_{RM}$	85	
Forward current	$I_F$	200	mA
Surge forward current, $t = 1 \mu s$	$I_{FS}$	4.5	A
Total power dissipation, $T_S = 85^\circ C$	$P_{tot}$	250	mW
Junction temperature	$T_j$	150	$^\circ C$
Storage temperature	$T_{stg}$	65 ...+150	

### Thermal Resistance

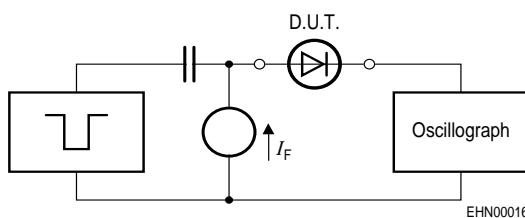
Junction - ambient 1)	$R_{thJA}$	$\leq 530$	K/W
Junction - soldering point	$R_{thJS}$	$\leq 260$	K/W

1) Package mounted on epoxy pcb 40mm x 40mm x 1.5mm / 0.5cm<sup>2</sup> Cu

**Electrical Characteristics** at  $T_A = 25^\circ\text{C}$ , unless otherwise specified.

Parameter	Symbol	Values			Unit
		min.	typ.	max.	
<b>DC characteristics</b>					
Breakdown voltage $I_{(\text{BR})} = 100 \mu\text{A}$	$V_{(\text{BR})}$	75	-	-	V
Forward voltage $I_F = 1 \text{ mA}$	$V_F$	-	-	715	mV
$I_F = 10 \text{ mA}$		-	-	855	
$I_F = 50 \text{ mA}$		-	-	1000	
$I_F = 150 \text{ mA}$		-	-	1250	
Reverse current $V_R = 70 \text{ V}$	$I_R$	-	-	2.5	$\mu\text{A}$
Reverse current $V_R = 25 \text{ V}, T_A = 150^\circ\text{C}$	$I_R$	-	-	30	nA
$V_R = 70 \text{ V}, T_A = 150^\circ\text{C}$		-	-	50	
<b>AC characteristics</b>					
Diode capacitance $V_R = 0 \text{ V}, f = 1 \text{ MHz}$	$C_D$	-	-	2	pF
Reverse recovery time $I_F = 10 \text{ mA}, I_R = 10 \text{ mA}, R_L = 100 \Omega$ , measured at $I_R = 1 \text{ mA}$	$t_{\text{rr}}$	-	-	6	ns

### Test circuit for reverse recovery time

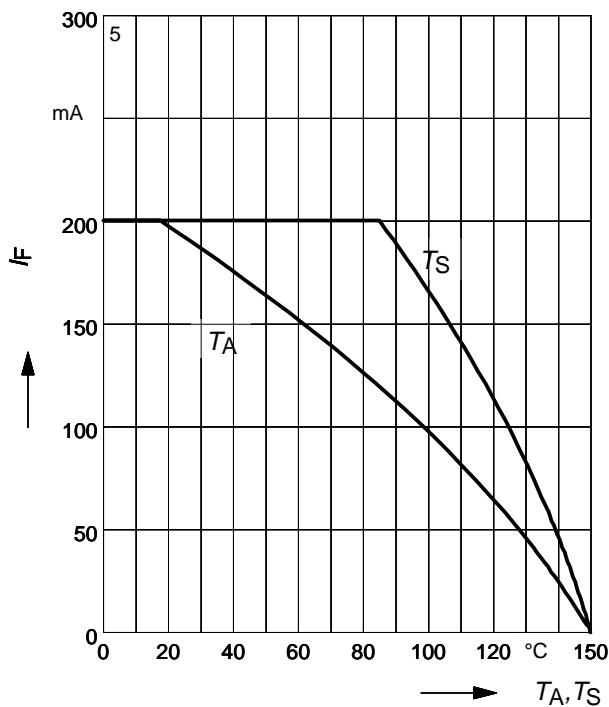


Pulse generator:  $t_p = 100\text{ns}$ ,  $D = 0.05$ ,  
 $t_r = 0.6\text{ns}$ ,  $R_i = 50\Omega$

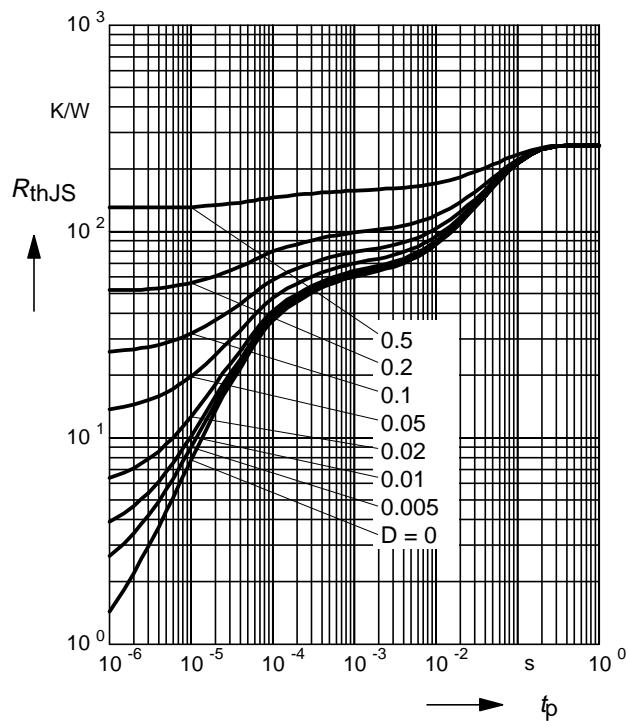
Oscilloscope:  $R = 50\Omega$ ,  $t_r = 0.35\text{ns}$ ,  
 $C \leq 1\text{pF}$

**Forward current  $I_F = f(T_A^*; T_S)$**

\* Package mounted on epoxy

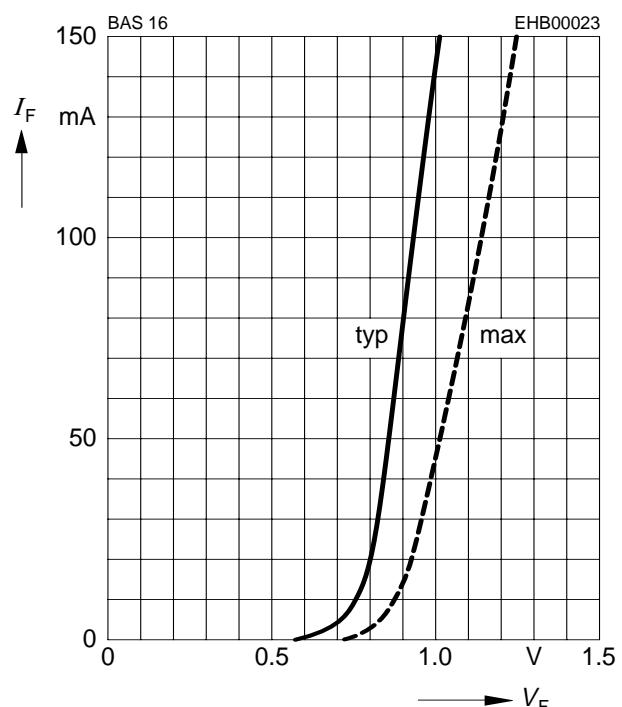


**Permissible Pulse Load  $R_{thJS} = f(t_p)$**



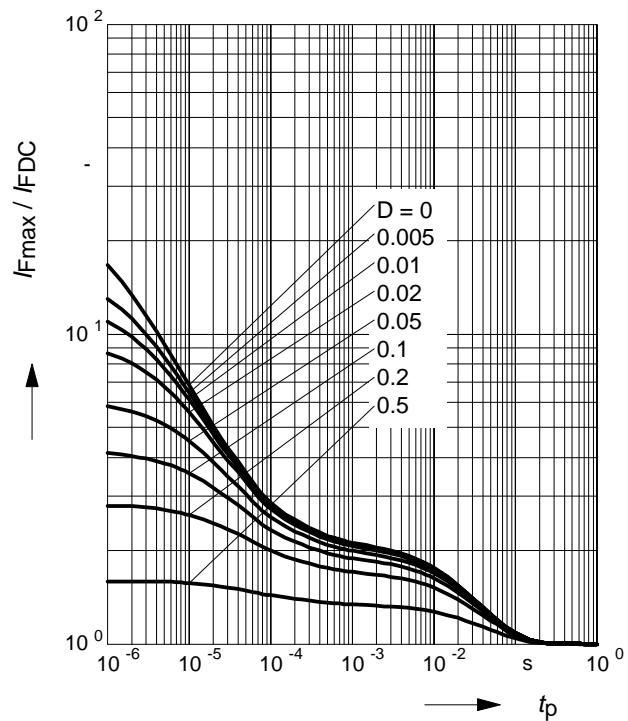
**Forward current  $I_F = f V_F$**

$T_A = 25^\circ\text{C}$

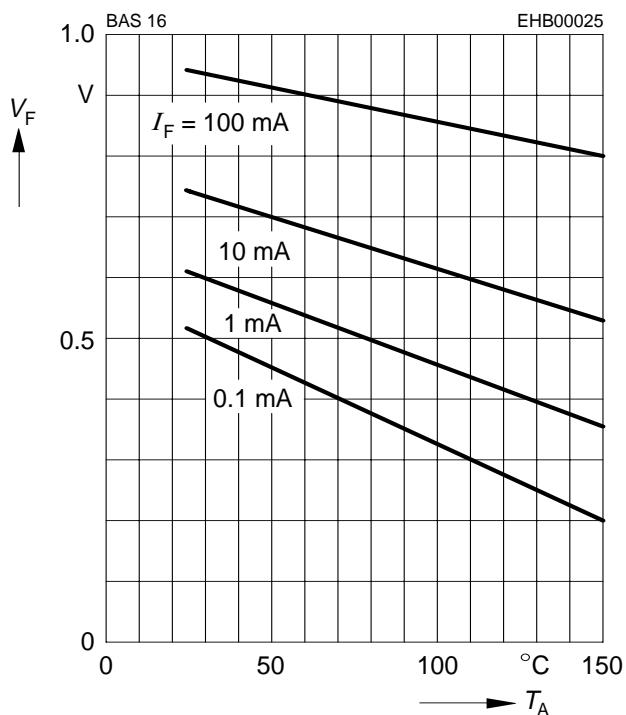


**Permissible Pulse Load**

$I_{Fmax} / I_{FDC} = f(t_p)$



**Forward voltage**  $V_F = f(T_A)$



**Reverse current**  $I_R = f(T_A)$

